# NSN 5961-01-065-9808

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## Inclosure Material:

Plastic

## Overall Length:

Between 0.568 inches and 0.615 inches

## **Overall Height:**

Between 0.160 inches and 0.190 inches

#### **Overall Width:**

Between 0.390 inches and 0.420 inches

## Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

## Unthreaded hole

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

5.0 breakdown voltage, emitter-to-base, collector open and 45.0 breakdown voltage, collector-to-emitter, base open

## **Current Rating Per Characteristic:**

10.00 amperes source cutoff current

## Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

## Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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